

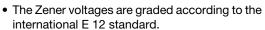
# Vishay Semiconductors

### **Zener Diodes**



#### **FEATURES**

- Silicon planar power Zener diodes
- For use in stabilizing and clipping circuits with high power rating





• These diodes are also available in the MELF

• Material categorization: for definitions of compliance

HALOGEN FREE

case75

please see www.vishay.com/doc?99912

### **LINKS TO ADDITIONAL RESOURCES**









PRIMARY CHARACT	VALUE UNIT   3.9 to 100 V   5 to 100 mA	
PARAMETER	VALUE	UNIT
V <sub>Z</sub> range nom.	3.9 to 100	V
Test current I <sub>ZT</sub>	5 to 100	mA
V <sub>Z</sub> specification	Pulse current	
Circuit configuration	Single	

ORDERING INFORMATION							
DEVICE NAME	EVICE NAME ORDERING CODE		MINIMUM ORDER QUANTITY				
ZPY3V9 to ZPY75	ZPY3V9 to ZPY75-series-TR	5000 (52 mm tape on 14" reel)	25 000/box				
ZPY3V9 to ZPY75	ZPY3V9 to ZPY75-series-TAP	5000 per ammopack (52 mm tape)	25 000/box				

PACKAGE							
PACKAGENAME   WEIGHT		MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS			
DO-41 (DO-204AL)	approx. 310 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C			

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Power dissipation	Valid provided that leads at a distance of 4 mm from case are kept at ambient temperature $t_p = 10 \text{ ms}$	P <sub>tot</sub>	1300	mW			
Zener current	See table "Characteristics"						
Junction to ambient air	Valid provided that leads at a distance of 4 mm from case are kept at ambient temperature $t_p = 10 \ \text{ms}$	R <sub>thJA</sub>	110	K/W			
Junction temperature		Tj	175	°C			
Storage temperature range		T <sub>stg</sub>	-55 to +175	°C			



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	ZENER VOLTAGE RANGE <sup>(2)</sup>		TEST CURRENT	REVERSE VOLTAGE		DYNAMIC RESISTANCE f = 1 kHz	ADMISSIBLE ZENER CURRENT (1)	TEMPERATURE COEFFICIENT OF ZENER VOLTAGE		
PART NUMBER	,	V <sub>Z</sub> at I <sub>ZT1</sub>		I <sub>ZT1</sub>	V <sub>R</sub> at I <sub>R</sub>		Z <sub>Z</sub> at I <sub>ZT1</sub>	Iz	TC <sub>VZ</sub> at I <sub>ZT1</sub>	
	V		mA	٧	μΑ		mA	10 <sup>-4</sup> /°C		
	MIN.	NOM.	MAX.			-	TYP.		MIN.	MAX.
ZPY3V9	3.7	3.9	4.1	100	-	0.5	4 (< 7)	290	- 7	2
ZPY4V3	4	4.3	4.6	100	1	0.5	4 (< 7)	260	- 7	3
ZPY4V7	4.4	4.7	5	100	ı	0.5	4 (< 7)	235	- 7	4
ZPY5V1	4.8	5.1	5.4	100	> 0.7	0.5	2 (< 5)	215	- 6	5
ZPY5V6	5.2	5.6	6	100	> 1.5	0.5	1 (< 2)	193	- 3	5
ZPY6V2	5.8	6.2	6.6	100	> 2.0	0.5	1 (< 2)	183	- 1	6
ZPY6V8	6.4	6.8	7.2	100	> 3.0	0.5	1 (< 2)	157	0	7
ZPY7V5	7	7.5	7.9	100	> 5.0	0.5	1 (< 2)	143	0	7
ZPY8V2	7.7	8.2	8.7	100	> 6.0	0.5	1 (< 2)	127	3	8
ZPY9V1	8.5	9.1	9.6	50	> 7.0	0.5	2 (< 4)	117	3	8
ZPY10	9.4	10	10.6	50	> 7.5	0.5	2 (< 4)	105	5	9
ZPY11	10.4	11	11.6	50	> 8.5	0.5	3 (< 7)	94	5	10
ZPY12	11.4	12	12.7	50	> 9.0	0.5	3 (< 7)	85	5	10
ZPY13	12.4	13	14.1	50	> 10	0.5	4 (< 9)	78	5	10
ZPY15	13.8	15	15.8	50	> 11	0.5	4 (< 9)	70	5	10
ZPY16	15.3	16	17.1	25	> 12	0.5	5 (< 10)	63	7	11
ZPY18	16.8	18	19.1	25	> 14	0.5	5 (< 11)	57	7	11
ZPY20	18.8	20	21.2	25	> 15	0.5	6 (< 12)	52	7	11
ZPY22	20.8	22	23.3	25	> 17	0.5	7 (< 13)	48	7	11
ZPY24	22.8	24	25.6	25	> 18	0.5	8 (< 14)	42	7	12
ZPY27	25.1	27	28.9	25	> 20	0.5	9 (< 15)	38	7	12
ZPY30	28	30	32	25	> 22.5	0.5	10 (< 20)	35	7	12
ZPY33	31	33	35	25	> 25	0.5	11 (< 20)	31	7	12
ZPY36	34	36	38	10	> 27	0.5	25 (< 60)	29	7	12
ZPY39	37	39	41	10	> 29	0.5	30 (< 60)	26	8	12
ZPY43	40	43	46	10	> 32	0.5	35 (< 80)	24	8	13
ZPY47	44	47	50	10	> 35	0.5	40 (< 80)	22	8	13
ZPY51	48	51	54	10	> 38	0.5	45 (< 100)	20	8	13
ZPY56	52	56	60	10	> 42	0.5	50 (< 100)	18	8	13
ZPY62	58	62	66	10	> 47	0.5	60 (< 130)	16	8	13
ZPY68	64	68	72	10	> 51	0.5	65 (< 130)	14	8	13
ZPY75	70	75	79	10	> 56	0.5	70 (< 160)	13	8	13

#### Notes

 $<sup>^{(1)}</sup>$  Valid provided that electrodes at a distance of 4 mm from case are kept at ambient temperature,  $t_p = 10 \text{ ms}$ 

 $<sup>\</sup>stackrel{\cdot}{\text{(2)}}$  Tested with pulses  $t_p = 5 \text{ ms}$ 



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### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

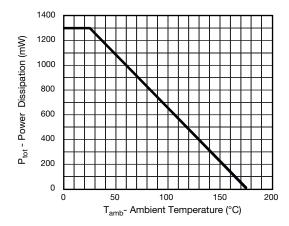


Fig. 1 - Admissible Power Dissipation vs. Ambient Temperature  $P_{tot} = f(T_{amb})$ 

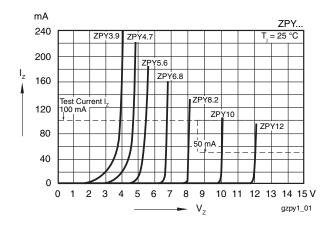


Fig. 3 - Typical Breakdown Characteristics

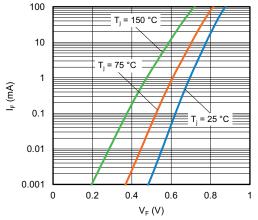


Fig. 2 - Typical Forward Current I<sub>F</sub> vs. Forward Voltage V<sub>F</sub>

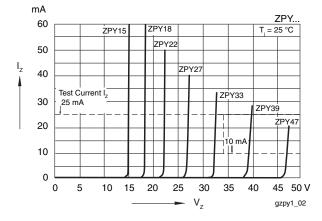
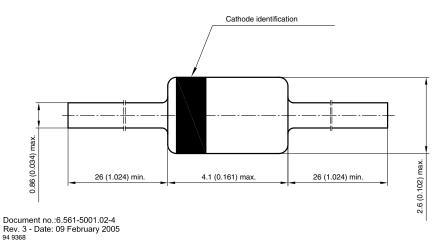


Fig. 4 - Typical Breakdown Characteristics

#### PACKAGE DIMENSIONS in millimeters (inches): DO-41 (DO-204AL)





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Vishay

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